

AP2306B 30V N-Channel Enhancement Mode MOSFET

• General Description

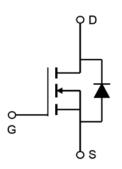
AP2306B combines advanced MOSFET technology with a low resistance package to provide extremely low $R_{\text{DS(ON)}}.$ This device is most suitable to load-switch or PWM applications.

Applications

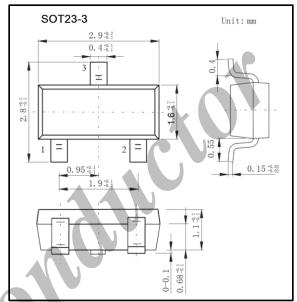
- DC/DC converter for portable devices
- Load switch

Product Summary

 $\begin{array}{ll} V_{DS} & 30V \\ R_{DS(ON)} \mbox{ (at $V_{GS}=10$V, $I_{D}=3.5$A)} & <57 m\Omega \\ R_{DS(ON)} \mbox{ (at $V_{GS}=4.5$V, $I_{D}=2.8$A)} & <94 m\Omega \end{array}$











Absolute Maximum Ratings (Ta = 25°C unless noted)

Parameter	Symbol	Rating	Unit		
Drain-Source Voltage	V_{DS}	30	V		
Gate-Source Voltage	V_{GS}	±20	V		
Continuous Drain Current *b	I_{D} (Ta = 25°C)	3.5			
Continuous Diani Current	I_{D} (Ta = 70°C)	2.8	A		
Pulsed Drain Current *a	I_{DM}	16	А		
Continuous Source Current (Diode Conduction) *b	I_{S}	1.25			
Power Dissipation *b	P_{D} (Ta = 25°C)	1.25	W		
rower dissipation	P_{D} (Ta = 70°C)	0.8			
Thermal Resistance. Junction-to-Ambient	$R_{\theta JA} (t \le 5s)^{*b}$	100	°C/W		
	R _{θJA} (Steady State) *c	130			
Junction Temperature	T_{J}	150	°C		
Storage Temperature Range	T_{STG}	-55 to 150			

Notes

^{*}a Pulse width limited by maximum junction temperature

^{*}b Surface Mounted on FR4 Board, t ≤ 5s.

^{*}c Surface Mounted on FR4 Board.

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• Electrical Characteristics (Ta = 25°C unless noted)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Drain-Source Breakdown Voltage	V_{DSS}	$I_D = 250 \mu A$, $V_{GS} = 0 V$	30			V	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =30V, V_{GS} =0V			0.5	4	
		V_{DS} =30V, V_{GS} =0V, T_{J} =55°C			10	μA	
Gate-Body Leakage Current	I_{GSS}	V_{DS} =0V, V_{GS} =±20V		KI	±100	nA	
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS} , I_D =250 μA	1			V	
On-state Drain Current	I _{D(ON)}	$V_{DS} \ge 4.5 \text{V}, V_{GS} = 10 \text{V}$	6			A	
		$V_{DS} \ge 4.5 V, V_{GS} = 4.5 V$	4				
Static Drain-Source On-Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =3.5A	2	46	57	mΩ	
		V _{GS} =4.5V, I _D =2.8A		70	94		
Forward Transconductance	$\mathbf{g}_{ ext{FS}}$	V_{DS} =4.5V, I_{D} =3.5A		6.9		S	
Diode Forward Voltage	V_{SD}	I_S =1.25A, V_{GS} =0V		08	1.2	V	
Input Capacitance *d	C_{iss}			555		pF	
Output Capacitance *d	C_{oss}	V_{GS} =0V, V_{DS} =15V, f=1MHz		120			
Reverse Transfer Capacitance *d	C_{rss}			60			
Gate Charge *d	Q_{g}	V_{GS} =5V, V_{DS} =15V, I_{D} =3.5A		4.2	7		
Total Gate Charge *d	Q_{gt}			8.5	20	nC	
Gate Source Charge *d	Q_{gs}	V_{GS} =10V, V_{DS} =15V, I_{D} =3.5A		1.9			
Gate Drain Charge *d	Q_{gd}			1.35			
Gate Resistance *d	R_{g}		0.5		2.4	Ω	
Turn-On Delay Time	$t_{D(on)}$			9	20		
Turn-On Rise Time	$t_{\rm r}$	V_{GEN} =10V, V_{DD} =15V, I_{D} =1A,		7.5	18	ns	
Turn-Off Delay Time	$t_{D(off)}$	$R_L=15\Omega$, $R_{GEN}=6\Omega$		17	35		
Turn-Off Fall Time	t_{f}			5.2	12		

Note

• Ordering Information

	Ordering Part Number	Package	MOQ
ĺ	AP2306B	SOT23-3	3,000 pcs / reel

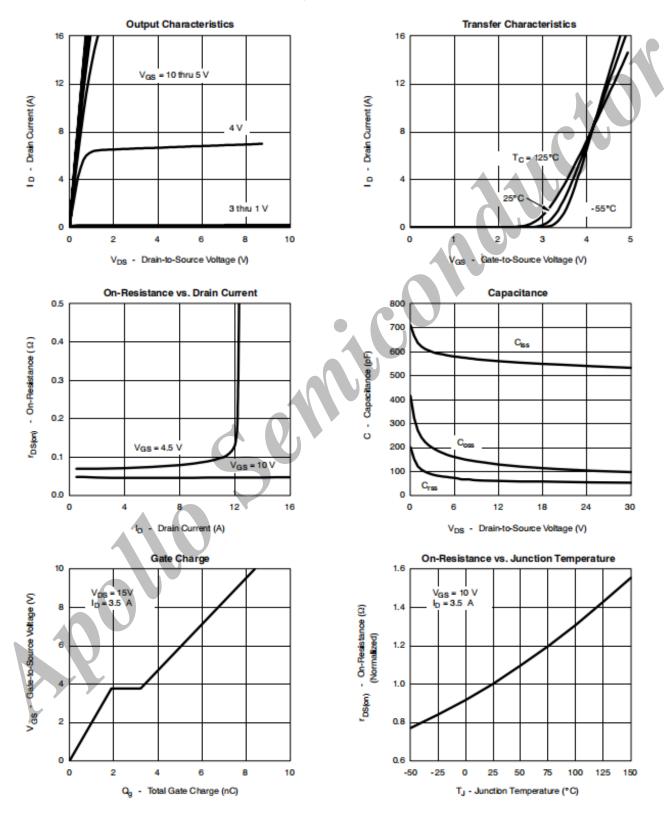
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^{*}d Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%



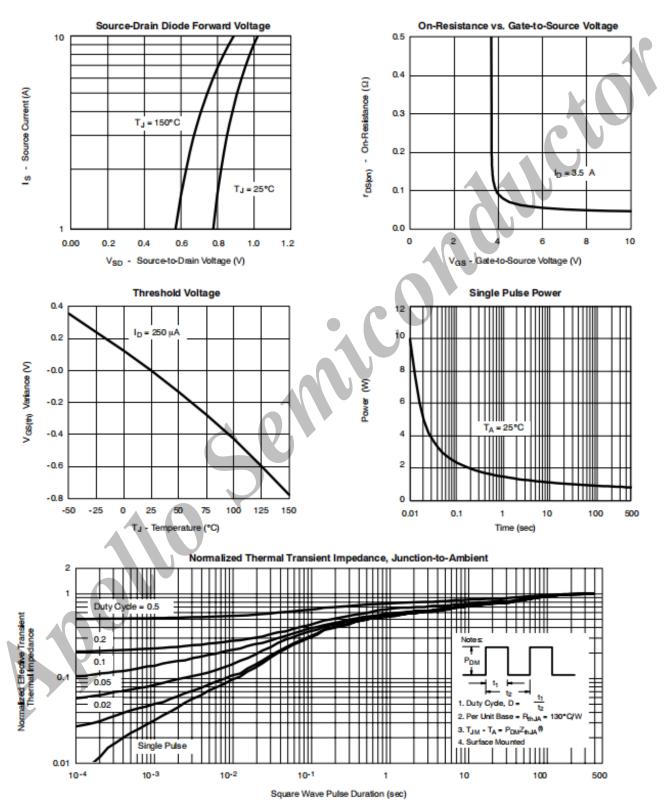


• Typical Characteristics (25°C unless noted)





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